

October 1987 Revised May 2002

# MM74C14 Hex Schmitt Trigger

#### **General Description**

The MM74C14 Hex Schmitt Trigger is a monolithic complementary MOS (CMOS) integrated circuit constructed with N- and P-channel enhancement transistors. The positive and negative going threshold voltages  $V_{T+}$  and  $V_{T-}$ , show low variation with respect to temperature (typ.  $0.0005\text{V}/^\circ\text{C}$  at  $V_{CC}=10\text{V})$ , and hysteresis,  $V_{T+}-V_{T-} \geq 0.2~V_{CC}$  is guaranteed.

All inputs are protected from damage due to static discharge by diode clamps to  $\mbox{V}_{\mbox{CC}}$  and GND.

#### **Features**

■ Wide supply voltage range: 3.0V to 15V■ High noise immunity: 0.70 V<sub>CC</sub> (typ.)

■ Low power: TTL compatibility:

0.4 V<sub>CC</sub> (typ.) 0.2 V<sub>CC</sub> guaranteed

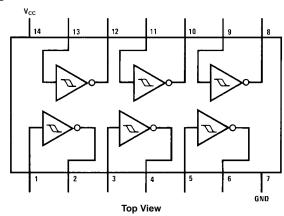
■ Hysteresis: 0.4 V<sub>CC</sub> (typ.): 0.2 V<sub>CC</sub> guaranteed

#### **Ordering Code:**

Order Number	Package Number	Package Description			
MM74C14M	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow			
MM74C14N	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide			

Devices also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

#### **Connection Diagram**



© 2002 Fairchild Semiconductor Corporation

DS005879

www.fairchildsemi.com

### Absolute Maximum Ratings(Note 1)

 $\begin{array}{lll} \mbox{Voltage at Any Pin} & -0.3 \mbox{V to V}_{\mbox{CC}} + 0.3 \mbox{V} \\ \mbox{Operating Temperature Range} & -55^{\circ}\mbox{C to } +125^{\circ}\mbox{C} \\ \mbox{Storage Temperature Range} & -65^{\circ}\mbox{C to } +150^{\circ}\mbox{C} \\ \end{array}$ 

Power Dissipation

Dual-In-Line 700 mW Small Outline 500mW

Operating V<sub>CC</sub> Range 3.0V to 15V

Absolute Maximum V<sub>CC</sub> 18V

Lead Temperature

(Soldering, 10 seconds) 260°C

**Note 1:** "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Temperature Range" they are not meant to imply that the devices should be operated at these limits. The Electrical Characteristics tables provide conditions for actual device operation.

#### **DC Electrical Characteristics**

Min/Max limits apply across the guaranteed temperature range unless otherwise noted

Symbol	Parameter	Conditions	Min	Тур	Max	Units
CMOS TO C	Mos		*	•		•
$V_{T+}$	Positive Going Threshold Voltage	$V_{CC} = 5V$	3.0	3.6	4.3	
		V <sub>CC</sub> = 10V	6.0	6.8	8.6	V
		V <sub>CC</sub> = 15V	9.0	10.0	12.9	1
$V_{T-}$	Negative Going Threshold Voltage	V <sub>CC</sub> = 5V	0.7	1.4	2.0	
		V <sub>CC</sub> = 10V	1.4	3.2	4.0	V
		V <sub>CC</sub> = 15V	2.1	5.0	6.0	1
$V_{T+} - V_{T-}$	Hysteresis	V <sub>CC</sub> = 5V	1.0	2.2	3.6	
		V <sub>CC</sub> = 10V	2.0	3.6	7.2	V
		V <sub>CC</sub> = 15V	3.0	5.0	10.8	Ī
V <sub>OUT(1)</sub>	Logical "1" Output Voltage	$V_{CC} = 5V, I_{O} = -10 \mu A$	4.5			V
		$V_{CC} = 10V, I_{O} = -10 \mu A$	9.0			† V
V <sub>OUT(0)</sub>	Logical "0" Output Voltage	$V_{CC} = 5V, I_{O} = 10 \mu A$			0.5	.,
		$V_{CC} = 10V, I_{O} = 10 \mu A$			1.0	V
I <sub>IN(1)</sub>	Logical "1" Input Current	V <sub>CC</sub> = 15V, V <sub>IN</sub> = 15V		0.005	1.0	μΑ
I <sub>IN(0)</sub>	Logical "0" Input Current	V <sub>CC</sub> = 15V, V <sub>IN</sub> = 0V	-1.0	-0.005		μΑ
Icc	Supply Current	V <sub>CC</sub> = 15V, V <sub>IN</sub> = 0V/15V		0.05	15	
		V <sub>CC</sub> = 5V, V <sub>IN</sub> = 2.5V (Note 2)		20		1 .
		V <sub>CC</sub> = 10V, V <sub>IN</sub> = 5V (Note 2)		200		μΑ
		V <sub>CC</sub> = 15V, V <sub>IN</sub> = 7.5V (Note 2)		600		Ī
CMOS/LPTT	LINTERFACE		<b> </b>		ı	1
V <sub>IN(1)</sub>	Logical "1" Input Voltage	$V_{CC} = 5V$	4.3			V
V <sub>IN(0)</sub>	Logical "0" Input Voltage	V <sub>CC</sub> = 5V			0.7	V
V <sub>OUT(1)</sub>	Logical "1" Output Voltage	74C, $V_{CC} = 4.75V$ , $I_{O} = -360 \mu A$	2.4			V
V <sub>OUT(0)</sub>	Logical "0" Output Voltage	74C, V <sub>CC</sub> = 4.75V, I <sub>O</sub> = 360 μA			0.4	V
	IVE (see Family Characteristics Data	Sheet) T <sub>A</sub> = 25°C (Short Circuit Current	:)			1
I <sub>SOURCE</sub>	Output Source Current	V <sub>CC</sub> = 5V, V <sub>OUT</sub> = 0V	-1.75	-3.3		mA
OOOROL	(P-Channel)					
I <sub>SOURCE</sub>	Output Source Current	V <sub>CC</sub> = 10V, V <sub>OUT</sub> = 0V	-8.0	-15		mA
	(P-Channel)					
I <sub>SINK</sub>	Output Sink Current	V <sub>CC</sub> = 5V, V <sub>OUT</sub> = V <sub>CC</sub>	1.75	3.6		mA
	(N-Channel)					
I <sub>SINK</sub>	Output Sink Current	V <sub>CC</sub> = 10V, V <sub>OUT</sub> = V <sub>CC</sub>	8.0	16		mA
	(N-Channel)	1	1			

Note 2: Only one of the six inputs is at  $\frac{1}{2}$  V<sub>CC</sub>; the others are either at V<sub>CC</sub> or GND.

## AC Electrical Characteristics (Note 3)

 $T_A = 25^{\circ}C, \ C_L = 50 \ \text{pF}, \text{ unless otherwise specified}$ 

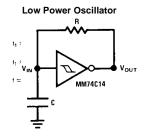
Symbol	Parameter	Conditions	Min	Тур	Max	Units
t <sub>PD0</sub>	Propagation Delay	V <sub>CC</sub> = 5V		220	400	n
t <sub>PD1</sub>	from Input to Output	V <sub>CC</sub> = 10V		80	200	ns
C <sub>IN</sub>	Input Capacitance	Any Input (Note 4)		5.0		pF
C <sub>PD</sub>	Power Dissipation Capacitance	Per Gate (Note 5)		20		pF

Note 3: AC Parameters are guaranteed by DC correlated testing.

Note 4: Capacitance is guaranteed by periodic testing.

Note 5:  $C_{PD}$  determines the no load AC power consumption of any CMOS device. For complete explanation see Family Characteristics Application Note—AN-90.

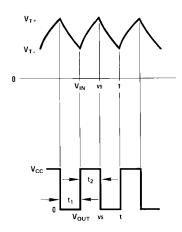
### **Typical Applications**



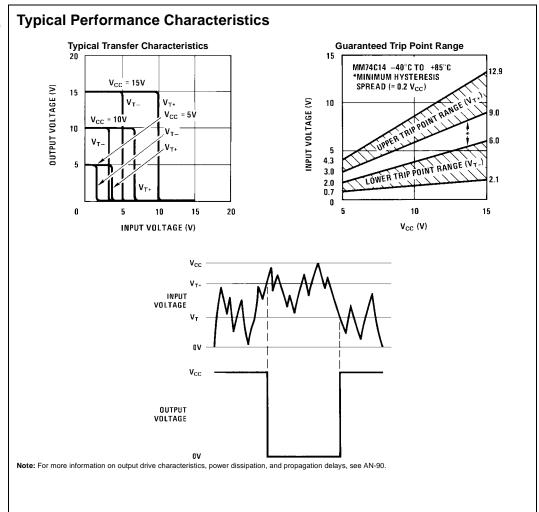
$$\begin{split} t_1 &\approx RC \; \ell \; n \frac{V_{T+}}{V_T} \\ t_1 &\approx RC \; \ell \; n \frac{V_{CC} - V_{T-}}{V_{CC} - V_{T+}} \\ f &\approx \frac{1}{RC \; \ell \; n \frac{V_{T+} \left(V_{CC} - V_{T-}\right)}{V_{T-} \left(V_{CC} - V_{T-}\right)}} \approx \frac{1}{1.7 \; RC} \end{split}$$

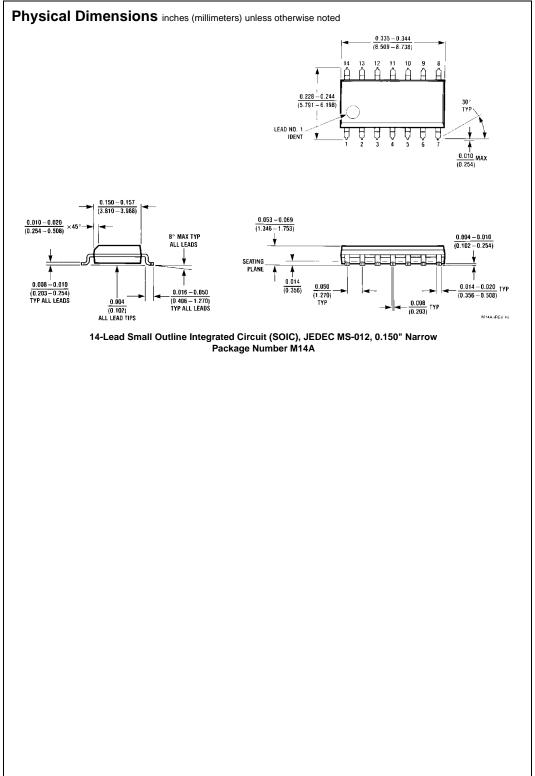
Note: The equations assume  $t_1 + t_2 \gg t_{pd0} + t_{pd1}$ 

V<sub>GC</sub> ----









5

#### Physical Dimensions inches (millimeters) unless otherwise noted (Continued) 0.740 - 0.770 (18.80 - 19.56)0.090 (2.286) 14 13 12 11 10 9 8 14 13 12 $0.250 \pm 0.010$ $\overline{(6.350 \pm 0.254)}$ PIN NO. 1 PIN NO. 1 IDEN1 1 2 3 4 5 6 7 1 2 3 IDENT $\frac{0.092}{(2.337)}$ DIA 0.030 MAX (0.762) DEPTH OPTION 1 OPTION 02 $0.135 \pm 0.005$ 0.300 - 0.320 $(3.429 \pm 0.127)$ $\overline{(7.620 - 8.128)}$ 0.065 0.145 - 0.200 0.060 (1.524) 4° TYP (1.651) (3.683 - 5.080) $\frac{0.008 - 0.016}{(0.203 - 0.406)} \text{ TYP}$ 95° ± 5 0.020 (0.508)0.125 - 0.150MIN $0.075 \pm 0.015$ $\overline{(3.175 - 3.810)}$ 0.280 $(1.905 \pm 0.381)$ (7.112)-MIN 0.014 - 0.023 $\frac{0.100 \pm 0.010}{(2.540 \pm 0.254)} \text{ TYP}$ (0.356 - 0.584)0.050±0.010 TYP $0.325 \,{}^{+\, 0.040}_{-\, 0.015}$ (1.270 - 0.254) $8.255 + 1.016 \\ -0.381$

14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide Package Number N14A

Fairchild does not assume any responsibility for use of any circuitry described, no circuit patent licenses are implied and Fairchild reserves the right at any time without notice to change said circuitry and specifications.

#### LIFE SUPPORT POLICY

FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF THE PRESIDENT OF FAIRCHILD SEMICONDUCTOR CORPORATION. As used herein:

- Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
- A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

www.fairchildsemi.com

www.fairchildsemi.com